## 2SC5813

## Silicon NPN epitaxial planar type

#### For DC-DC converter

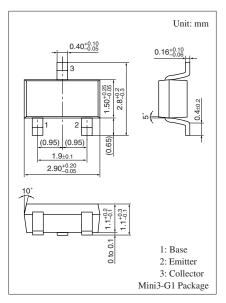
#### ■ Features

- $\bullet$  Low collector to emitter saturation voltage  $V_{\text{CE}(\text{sat})}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector to base voltage	$V_{CBO}$	80	V
Collector to emitter voltage	V <sub>CEO</sub>	80	V
Emitter to base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	1.5	A
Peak collector current	$I_{CP}$	3	A
Collector power dissipation *	P <sub>C</sub>	600	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Note) \*: Measuring on ceramic substrate at 15 mm  $\times$  15 mm  $\times$  0.6 mm

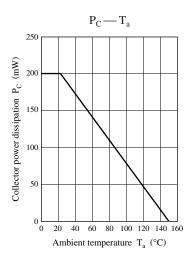


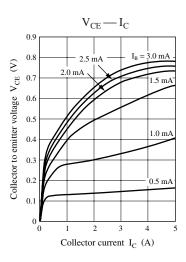
Marking symbol: 5H

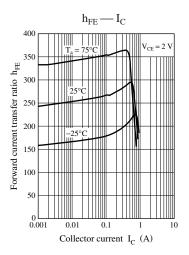
### ■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

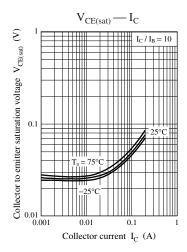
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_C = 10 \mu\text{A},  I_E = 0$	80			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	80			V
Emitter to base voltage	V <sub>EBO</sub>	$I_E = 10 \ \mu A, \ I_C = 0$	5			V
Collector cutoff current	$I_{CBO}$	$V_{CB} = 40 \text{ V}, I_{E} = 0$			0.1	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	200			_
Collector to emitter saturation voltage *	V <sub>CE(sat)</sub>	$I_C = 1 \text{ A}, I_B = 20 \text{ mA}$		350	500	mV
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		15	25	pF
Gain bandwidth product	$f_T$	$V_{CB} = 10 \text{ V}, I_{E} = -50 \text{ mA}, f = 200 \text{ MHz}$		180		MHz

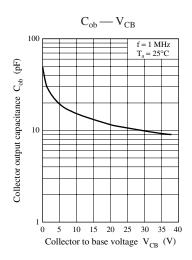
Note) \*: Pulse measurement











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